NSN 5961-00-784-7707

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Inclosure Material:
Metal
Overall Diameter:
0.260 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 collector to base voltage, dc and 30.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, dc
Power Rating Per Characteristic:
3.0 watts small-signal input power, common-collector preset
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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